



**KTH Electrical Engineering**

# MEMS tunable polarization rotator for optical communication

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# Contents

<b>1</b>	<b>Introduction</b>	<b>1</b>
1.1	Light for communication using optical fibers . . . . .	1
1.2	Silicon photonics for optical communication . . . . .	2
1.3	Motivation . . . . .	3
1.4	Objectives . . . . .	4
1.5	Outline of this thesis . . . . .	4
<b>2</b>	<b>State of the art</b>	<b>6</b>
2.1	Optical waveguide theory . . . . .	6
2.1.1	Maxwell's equations . . . . .	6
2.1.2	Optical waveguides . . . . .	9
2.1.2.1	Planar waveguides . . . . .	9
2.1.2.2	Channel waveguides . . . . .	10
2.1.3	Eigenvalue and wave modes . . . . .	11
2.1.4	Optical polarization and transverse modes . . . . .	12
2.1.4.1	TE mode . . . . .	13
2.1.4.2	TM mode . . . . .	14
2.1.5	Confinement factor . . . . .	14
2.1.6	Jones calculus . . . . .	14
2.1.6.1	Jones vector . . . . .	14
2.1.6.2	Jones matrix . . . . .	15
2.1.7	Jones matrix for polarizing optical systems . . . . .	15
2.1.7.1	Polarizer . . . . .	16
2.1.7.2	Wave plates . . . . .	16
2.1.8	Poincaré sphere and state of polarization . . . . .	16
2.1.9	Stoke's parameter . . . . .	17
2.2	Tuning optical waveguide . . . . .	19
2.2.1	Thermal mechanism . . . . .	19
2.2.2	Liquid crystals . . . . .	19
2.2.3	Current injection . . . . .	19
2.2.4	MEMS . . . . .	19
2.3	Polarization rotator (PR) . . . . .	20
2.3.1	Optical fiber PR . . . . .	20
2.3.2	Integrated circuit PR . . . . .	20
2.3.2.1	Passive PR . . . . .	20
2.3.2.2	Active PR . . . . .	20
2.3.2.3	Comparative analysis of available polarization rotator . .	20

<b>3</b>	<b>Design and simulation</b>	<b>21</b>
3.1	Approach . . . . .	21
3.2	Designing the experiment . . . . .	21
3.2.1	Design principle . . . . .	21
3.2.2	Use case: Active polarization rotator . . . . .	21
3.3	Choice of simulation . . . . .	21
3.4	Simulation results and analysis . . . . .	21
<b>4</b>	<b>Fabrication</b>	<b>22</b>
<b>5</b>	<b>Interpreting the design</b>	<b>23</b>
5.1	Experimental setup for measurement . . . . .	23
5.2	Optical coupling . . . . .	23
5.3	Results . . . . .	23
5.4	Analysis . . . . .	23
<b>6</b>	<b>Conclusions</b>	<b>24</b>
<b>7</b>	<b>Limitations and future work</b>	<b>25</b>
7.1	Limitations . . . . .	25
7.2	Future work . . . . .	25
	<b>Abbreviations</b>	<b>27</b>
	<b>Bibliography</b>	<b>29</b>

# Chapter 1

## Introduction

### 1.1 Light for communication using optical fibers

Communication and collective thinking are the key to the development of human civilization. This is driven by data - “The new oil of this digital era”. With the advent of Internet of Things (IoT), it has been estimated that by 2020 there will be 26 billion connected devices [1], and all that can be connected will be connected. Today, only about 40% [2] of the world’s population use the internet and the amount of data produced per minute through different social media platforms is already growing exponentially.

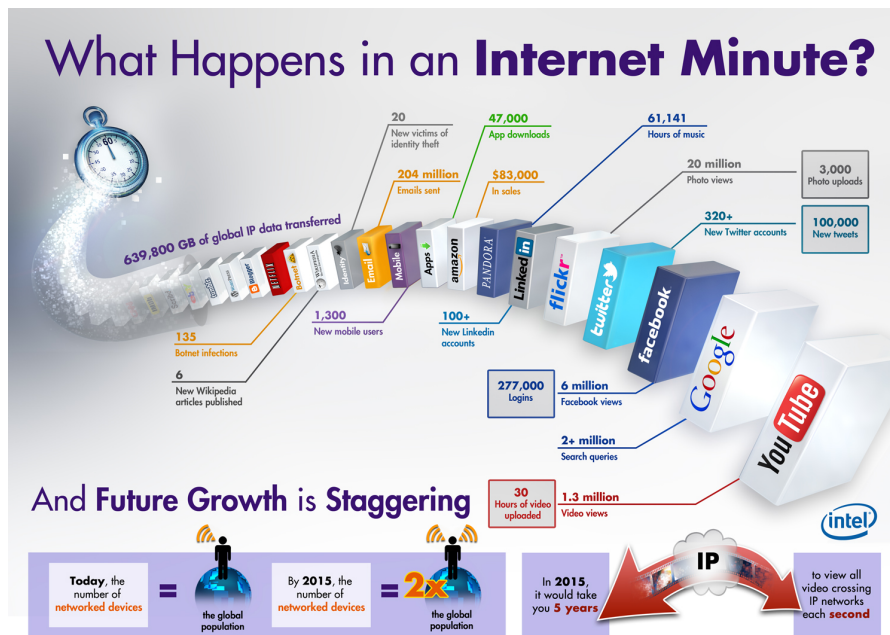


Figure 1.1: What happens on internet per minute [3]

Eventually, as more and more people use the different Information and communication technology (ICT) services, this data growth will be exponential.

Also, with the advent of smart devices, there has been a huge surge in data traffic all over the world. It has been estimated in Ericsson’s mobility report [4] that 70% of

## Data Traffic – Split Per Device

in Mobile PC/Router/Tablet | Smartphone | Feature/Basic Phone

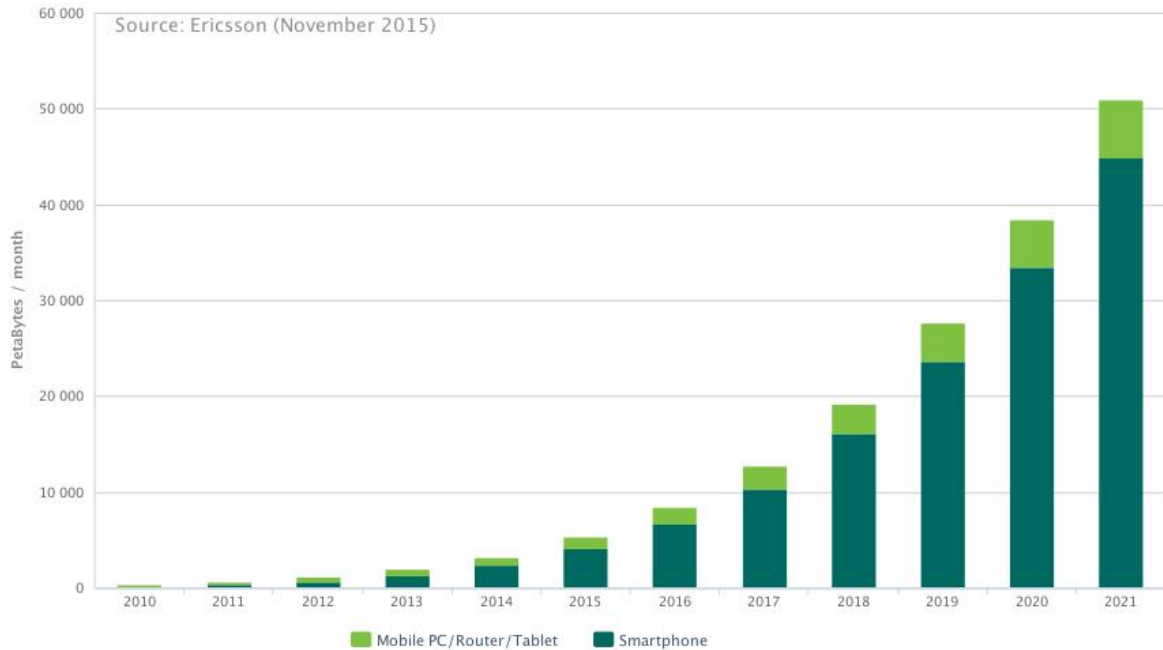


Figure 1.2: Data traffic growth forecast by 2020, as per Ericsson, generated using [5] [3]

world's population will use smart-phones by 2020 and 90% of the world's population over 6 years old will have a mobile phone by 2020.

Currently, the telecommunications industry is moving towards IP Multimedia Subsystem (IMS) core networks which is a transition towards full IP based networks. So how is this traffic managed? The answer is the optical fiber, which serves as the backbone of all the communication systems.

## 1.2 Silicon photonics for optical communication

The performance of optical fiber network is unprecedented and it is this backbone which gives us an unfathomable user experience. The current internet architecture has already pushed the optical fiber to the network edges and the trend is to push it as closer to the processor as possible. This has already opened up a new trend of “Siliconizing photonics” based on the decades of research from microelectronics industry. The electronics industry has pushed the boundaries of the processing speed of Integrated circuit(s) (IC) after the discovery of semiconductors, and are currently at the edge where Moore's Law is nearing its end. Transmission of signals through copper interconnects would slow things down. Although, with the current technology we have a good processing power but the interconnects between the ICs, which use copper, take significantly more time to transfer data. Think of a data center processing tera-bytes of data per minute, where

interconnects between processors can add up to a significant delay. These losses can be overcome by substituting optical interconnects using the current technology which can also operate at low power and better efficiency.

## 1.3 Motivation

The movement of data in a computer is almost the equivalent of movement of traffic in a city, where data flows fast in the congested microprocessor but is delayed in the interconnects. Intel processor speed and bus speed comparison [6] shows that although we have achieved good processing speed, the interconnects always find difficulty in catching up with the processing speed. Obviously, the closer engineers can bring the optical superhighway to the microprocessor, the fewer copper bottlenecks can occur. Until recently, exponential increases in the speed, efficiency, and processing power of conventional electronic devices were achieved largely through the downscaling and clustering of components on a chip. However, this trend toward miniaturization has yielded unwanted effects in the form of significant increases in noise, power consumption, signal propagation delay and aggravates already to serious thermal management problems. Alternatively, the wires can be made fatter, but then you'll run out of space and the packing density will be inefficient. As a result, traditional microelectronics will soon fall short of meeting market needs, inhibited by the thermal and bandwidth bottlenecks inherent in copper wiring. Photons don't suffer from these limitations; their biggest problems are absorption and attenuation, neither of which is an issue over the distances inside a computer, or even across a room. Today Silicon Photonics [7] Technology is a new approach to make optical devices out of silicon and use light (photons) to move huge amounts of data at very high speeds with extremely low power over a thin optical fiber rather than using electrical signals over a copper wire. Since, already enough capital investments has been done on perfecting the current fabrication technology and infrastructure, engineers are working on creating monolithic design of integrated circuits which use light in place of electric signals. Organizations are trying to bridge this gap by creating highly integrated photonic and electronic components that combine the functionality of conventional Complementary metal-oxide semiconductor (CMOS) circuits with the significantly enhanced system performance of photonic solutions. By allowing for the seamless integration of optical and electronic components on silicon-based substrates, this technology holds the key to fulfilling market needs for higher bandwidth and processing speed at lower power and cost.

Silicon Photonics is an emerging market and researchers are actively working on creating monolithic IC design with optical components to cope up with the future demands [8]. Researchers are coming up with new avenues indicating that fiber information capacity can be notably increased over previous estimates [9] which can double fiber optic capacity. The silicon photonics market is estimated to grow to 700 million USD by 2024 [10] with a Compound annual growth rate (CAGR) of 38%. Photonic devices made on Silicon on Insulator (SOI) platform is compatible with CMOS electrical circuits since they are based on same material. It is also promising in developing on-chip integration for

telecommunications applications and servers in data centers [11]. Various kinds of silicon photonic devices like switches [12, 13, 14], modulators [15, 16], photodetectors [17, 18], delay lines [19, 20], sensors [21, 22, 23] etc. have been reported till date. All these things have corroborated interest into silicon photonics which are based on SOI platform.

However, these photonic devices based on SOI waveguides are sensitive to polarization due to large structural birefringence, which might induce Polarization dependent loss (PDL), Polarization mode dispersion (PMD), and Polarization dependent wavelength characteristics (PD $\lambda$ ) limiting their usability. To overcome these challenges Polarization rotator (PR) are engineered on SOI for Optoelectronic integrated circuit (OEIC) and various designs have already been demonstrated [24, 25, 26, 27, 28, 29, 30] which will be discussed in later sections. The main principle of these proposed solutions are based on varying Refractive index (RI) by introducing asymmetry in the waveguide structure which is not tunable. Also, in some cases the designs [31], if used in commercial applications for miniature interconnects, would incur inefficient packing density since too much space is required to achieve high and robust tuning. Apart from that there might also be thermo-optic induction problem which might change phase of the wave in other waveguides in high compact density environment as silicon is highly susceptible to thermal changes [32]. Also, Tunable polarization rotator (TPR) have been reported which works on the principle of Berry's phase, a quantum-mechanical phenomenon of purely topological origin [33]. But, since the design is based on out of plane waveguides it might be difficult to achieve efficient mass production without a complex manufacturing process. The general goal of the thesis work is to realize efficient TPR using Microelectromechanical systems (MEMS), to achieve improvement over the current available research solutions, to cater needs of the future industry.

## 1.4 Objectives

**Main objective:** To design and fabricate low power TPR based on MEMS tuning.

**Sub objectives:** The other areas which will be addressed are:

- ☐ Feasibility of the idea and the strategy to design the PR.
- ☐ Design and simulation of the device.
- ☐ Fabrication and characterization of the MEMS tunable PR.

## 1.5 Outline of this thesis

The outline of the thesis is as follows: Background, motivation and the research questions being addressed, is discussed in Chapter 1. In Chapter 2, the current state of art for the available solution is discussed along with the background literature required. Here, also the working principle of the current available design are explained along with the areas which can be improved. Chapter 3 discusses about the design of the final system and

the results obtained about the simulation setup. In Chapter 4, documentation about the fabricated design is provided along with currently available standard fabrication technologies. Results and characterization are an important part of the work, which is discussed in Chapter 5. Finally, Chapter 6 and 7 discusses about the conclusion and future work possibilities respectively along with the known limitations of the system if any.



# 2

## Chapter 2

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# State of the art

To understand the available PR it is important to look into the basic concepts of waveguides and the mathematics behind the propagation of Electromagnetic (EM) waves in waveguides. It is also necessary to understand tuning of optical waveguides using different mechanisms to achieve optical polarization. Finally, the currently available PRs and their underlying concepts are discussed.

## 2.1 Optical waveguide theory

Light can travel through dielectric waveguide. To comprehend the situation we need to look at physical properties of light and waveguides. The basic understanding of Maxwell's equations are required to combine the electric fields and magnetic fields to combine into a wave equation. Since, the optical system changes polarization we need a formal definition of the different State of polarization (SOP), described using Jones calculus. Moreover, the transition from one SOP to another, can be defined formally on the Poincaré sphere.

### 2.1.1 Maxwell's equations

EM radiation is the radiant energy released by varying EM field. Light is EM wave at very high frequency. The frequency of visible light falls in between IR and UV EM wave. James Clerk Maxwell discovered that he could combine four simple equations, which had been previously discovered, along with a slight modification to describe self-propagating waves of oscillating electric and magnetic fields [35]. The understanding of propagating of light waves using Maxwell's equations in a dielectric medium, is the key to the construction of waveguides. Maxwell's equations relate the electric field  $E$  (V/m), magnetic field  $H$  (A/m), charge density  $\rho$  (C/m<sup>3</sup>), and current density  $J$  (A/cm<sup>2</sup>).

- **Maxwell's first equation (Gauss' Law):** The net electric flux through any closed surface is equal to  $\frac{1}{\epsilon_m}$  times the charge density within that closed surface.

$$\nabla \cdot E = \frac{\rho}{\epsilon_m} \quad (2.1)$$

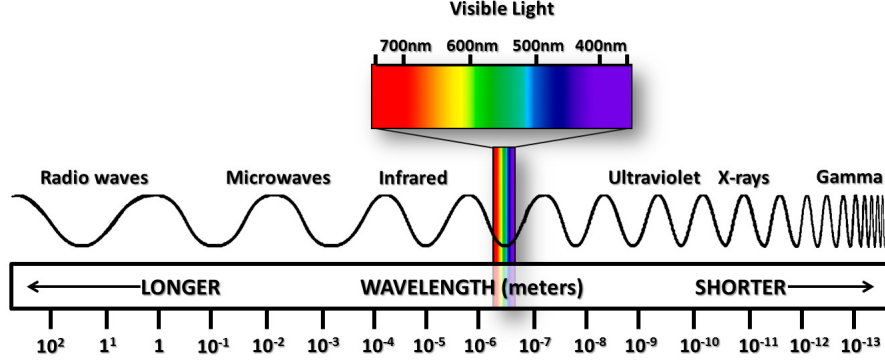


Figure 2.1: The EM wave spectrum

where  $\epsilon_m$  the permittivity of the medium, and del operator,  $\nabla$ , is given by:

$$\nabla = \left( \frac{\partial i}{\partial x}, \frac{\partial j}{\partial y}, \frac{\partial k}{\partial z} \right) \quad (2.2)$$

where i, j and k are unit vectors in the x, y and z directions respectively.

- **Maxwell's second equation (Gauss' Law for magnetic field):** The net magnetic flux through a closed surface is always zero since magnetic monopoles do not exist.

$$\nabla \cdot H = 0 \quad (2.3)$$

- **Maxwell's third equation (Faraday's law):** Induced electric field around a closed path is equal to the negative of the time rate of change of magnetic flux enclosed by the path.

$$\nabla \times E = -\mu_m \frac{\partial H}{\partial t} \quad (2.4)$$

where  $\mu_m$  is the magnetic permeability of the medium.

- **Maxwell's fourth equation (Modification of Ampere's law):** The fourth equation states that magnetic fields can be generated in two ways: by electric current (this was the original "Ampere's law") and by changing electric fields (this was "Maxwell's addition") [36].

$$\nabla \times H = J + \epsilon_m \frac{\partial E}{\partial t} \quad (2.5)$$

These equations combine into the wave equation after some mathematical calculations.

$$\nabla^2 E - \mu_m \epsilon_m \frac{\partial^2 E}{\partial t^2} = \mu_m \frac{\partial J}{\partial t} + \frac{\nabla \rho}{\epsilon_m} \quad (2.6)$$

using the curl of curl identity operation given by:

$$\nabla^2 E = \nabla(\nabla \cdot E) - \nabla \times (\nabla \times E) \quad (2.7)$$

A general solution to the equation 2.6 in free space, in absence of charge gives the following solution:

$$\vec{E}(z, t) = E_0(x, y)e^{i(k_0 z \pm \omega t)} \quad (2.8)$$

where  $z$  is direction of propagation of wave in Cartesian coordinates, phase,  $\phi = k_0 z \pm \omega t$  and wave vector propagation constant,  $k_0 = \frac{\partial \phi}{\partial t} = \frac{2\pi}{\lambda}$ , in the direction of propagation of the wave. Propagation constant in medium varies according to  $n$ , the effective RI of the medium and is given by:

$$k = nk_0 \quad (2.9)$$

where,

$$n = \sqrt{\epsilon_m \mu_m} \quad (2.10)$$

Similar calculations for the magnetic field,  $H$  in free space yields,

$$\vec{H}(z, t) = H_0(x, y)e^{i(k_0 z \pm \omega t)} \quad (2.11)$$

In the Fig. 2.2 the electric field and magnetic field propagate in directions perpendicular to each other. Moreover, the direction of propagation is also transverse to the EM field. Hence it is called Tansverse Electromagnetic (TEM) wave.

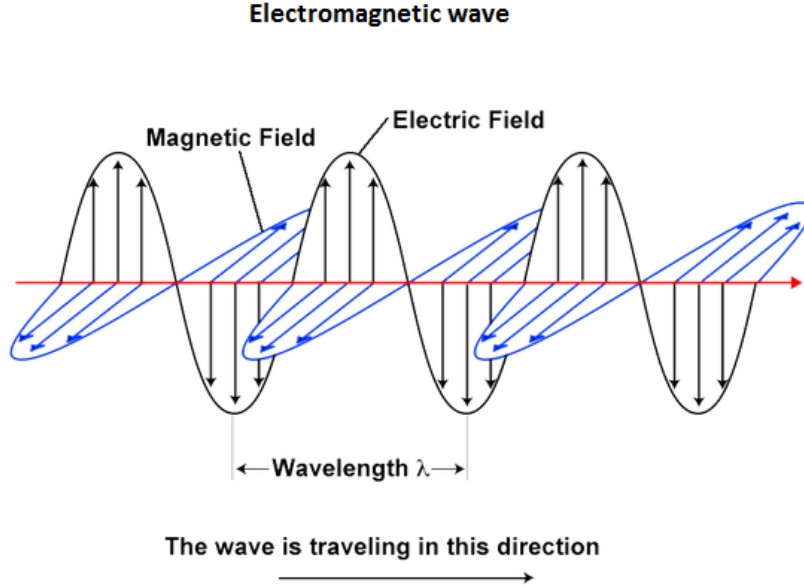


Figure 2.2: Propagation of EM wave

## 2.1.2 Optical waveguides

Waveguide is the essential element of every photonic circuit which can be characterized by the number of dimensions in which light is confined inside it [37]. A planar waveguide confines light in 1-D, which is simple for understanding of the wave propagation using Maxwell's equations. However, for practical applications 2-D confinement is necessary and that is why channel waveguides are used. Structures like photonic crystals even have 3-D confinement properties.

### 2.1.2.1 Planar waveguides

A simple planar waveguide consists of a high-indexed medium with height  $h$  surrounded by lower indexed materials on the top and bottom sides. The RI of the film,  $n_f$  (generally made from Si) is greater than the RI of the materials on the other sides. The RI of the substrate in lower cladding is  $n_s$ , (generally made from  $\text{SiO}_2$ ) whereas, RI of the substrate in upper cladding is  $n_c$  (generally which is air).

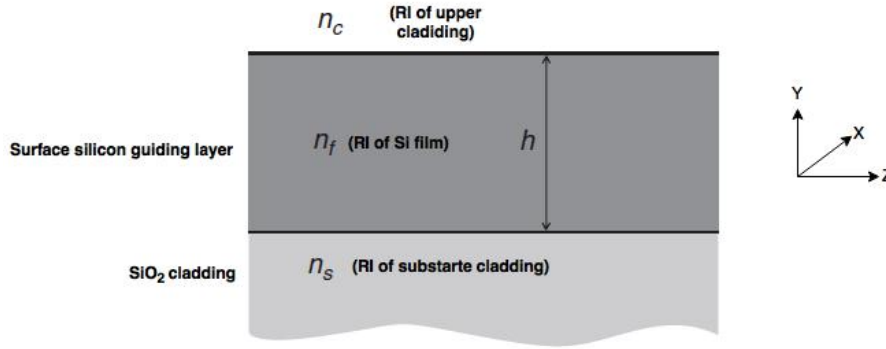


Figure 2.3: A typical planar waveguide where the film is infinite in XZ-plane

For planar waveguides the wave equation for electric field 2.8 and magnetic field can be rewritten as 2.11 follows:

$$\begin{cases} \vec{E}(z, t) = E_x(y)e^{i(k_0 z \pm \omega t)} \\ \vec{H}(z, t) = H_x(y)e^{i(k_0 z \pm \omega t)} \end{cases} \quad (2.12)$$

since in X-direction the film is infinite. After using the homogeneous wave equations for a planar waveguide the following Tansverse Electric (TE) and Tansverse Magnetic (TM) mode equations can be deduced:

$$\begin{cases} \nabla^2 E_x(y) + (k_0^2 n(y)^2 - k^2) E_x(y) = 0 \\ \nabla^2 H_x(y) + (k_0^2 n(y)^2 - k^2) H_x(y) = 0 \end{cases} \quad (2.13)$$

where RI depends only on a single Cartesian coordinate  $n = n(y)$ . These equations can be solved using the various boundary conditions of the waveguides which help in

deducing the nature of propagation of the wave in TE and TM mode. Different kinds of numerical methods like Finite element modeling (FEM), Finite difference time domain (FDTD), Beam propagation method (BPM) have been developed to decipher the nature of light propagation in waveguides.

### 2.1.2.2 Channel waveguides

As mentioned earlier channel waveguides provide confinement in 2-D which helps in depicting more practical waveguides. The three main types of channel waveguides are rib, strip and buried waveguides. As depicted in 2.4a, 2.4b, 2.4c the different conceptual structures of the waveguides can be envisaged. While the rib and strip waveguides are designed using etching technique, the buried waveguide mostly relies on diffusion and epitaxial growth technique for its fabrication.

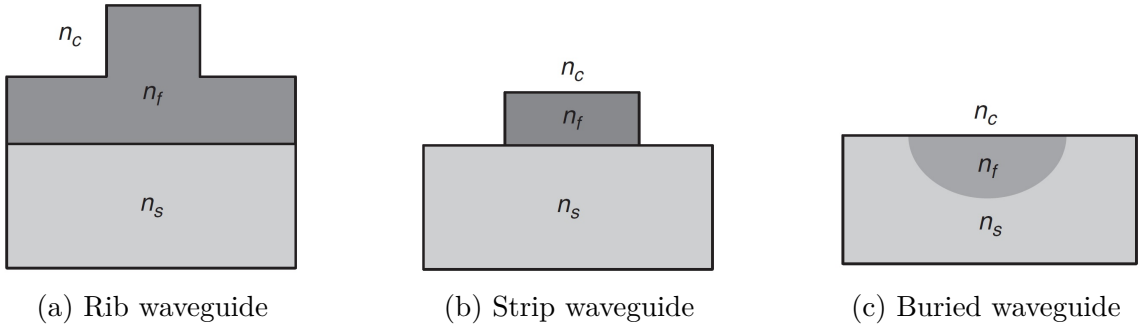


Figure 2.4: Different kinds of design for channel waveguides

- **Design rules of rib waveguides:** While designing these waveguides each of these have specific design rules for optimum performance and low-loss coupling, which has been standardized after years of research [37]. The Single-mode condition (SMC) for *rib waveguides* is as follows:

$$\frac{W}{H} \leq 0.3 + \frac{r}{\sqrt{1-r^2}}, \quad \text{for } (0.5 \leq r < 1) \quad (2.14)$$

where  $W$ =waveguide width,  $H$ =rib height,  $r$  is ratio of slab height to overall rib height.

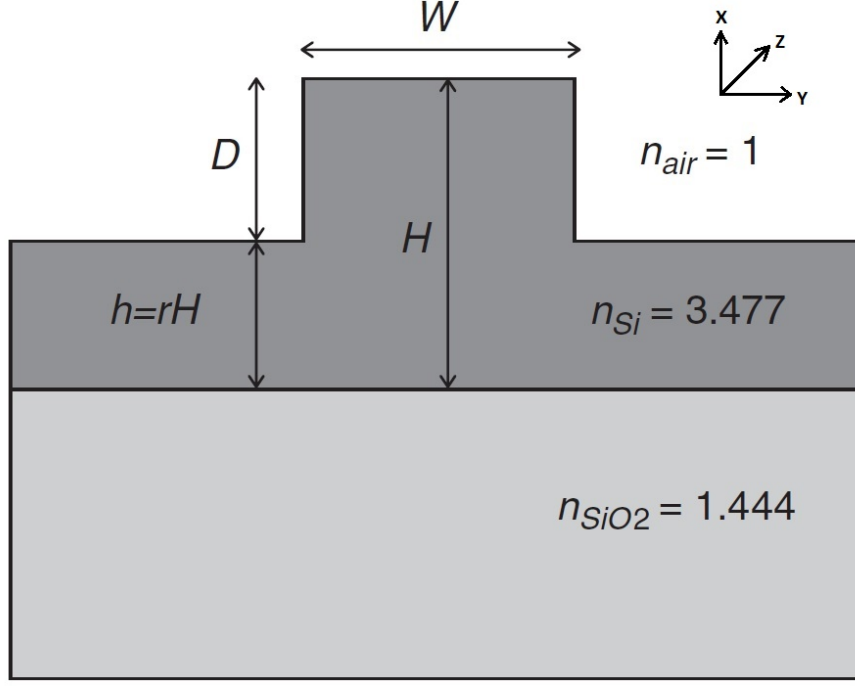


Figure 2.5: Rib waveguide design rules

The main requirements of the waveguide to cater the propagation of waves is that the dimension of the waveguide has to be more than the wavelength of the propagating wave. However, depending on the required structure the design rules may change which can be found using simulation.

- **Design rules of strip waveguides:** In mode confinement of light in optical waveguides the effective mode RI is important. Strip waveguides offer more high RI contrast in comparison to Rib waveguides. This can help in realization of ultra-dense photonic circuits because of high effective mode confinement. This can also achieve small bends which can improve the characterization of different monolithic optical circuits. In general a mix of rib and strip waveguides are used to achieve the desired circuitry, since sometimes the side walls cannot be etched in a perfectly smooth way causing greater evanescent fields from the waveguides introducing unnecessary coupling and losses. Using simulation for the desired scenario the robust values of the dimensions can be achieved.

### 2.1.3 Eigenvalue and wave modes

In general, the electric field in the wave equation in 2.8 can be written in its constituent parts in Cartesian coordinates as:

$$\vec{E} = E_x i + E_y j + E_z k \quad (2.15)$$

If the wave propagates towards z-direction through any waveguide medium and is a TEM wave front then we will have a constant electric field vector in the z-direction. In this case there will be different solutions for the propagation constant,  $k$  in x and y directions. Now for each solution we can also get certain discrete angles at which the electric field can travel through the medium, which infers that light can propagate only at certain discrete angles through any dielectric medium. Each allowed solution is referred to as the *mode of propagation* and are basically the different eigenvalues of the propagation vector.

The eigenvalues provide the different acceptance angles at which light can be inserted into the waveguide, resulting in different modes in the waveguide. Depending on the dimensions of the waveguide, various modes can be found which are basically the different eigenvalues of the wave solution 2.8 and 2.11. For example, when light travels through optical fibers different modes can be visualized as follows in Fig. 2.6.

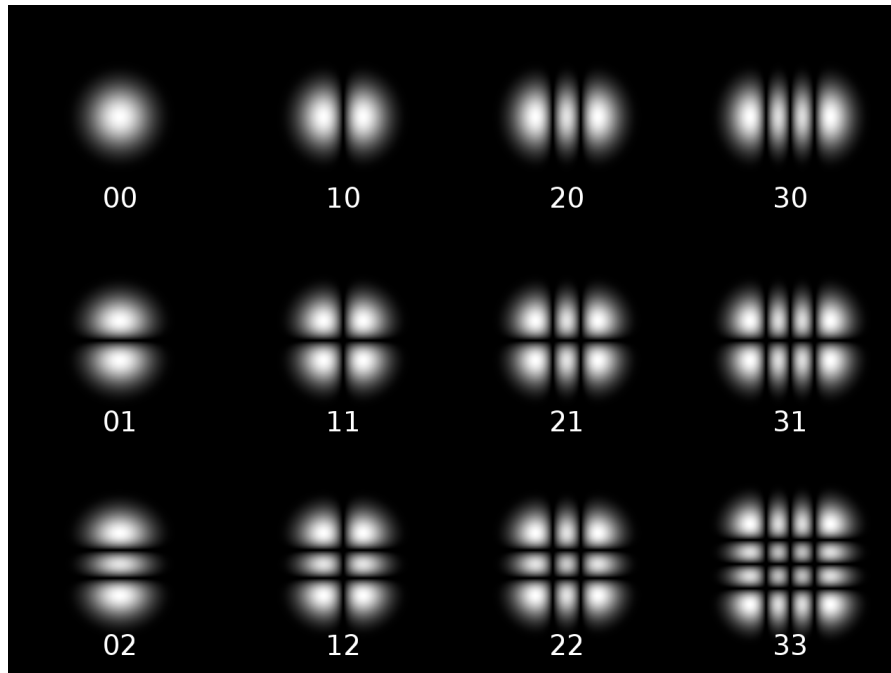


Figure 2.6: Rectangular transverse mode patterns TE(mn)

#### 2.1.4 Optical polarization and transverse modes

Single mode waveguide are most used for data transmission. Optical fibers generally operate at 1550 nm wavelength in single mode fundamental TE or TM mode communication. Polarization affects the propagation of EM fields at infrared. Hence, the waveguides must cater polarization into its design. *Polarization* is the direction of the electric field associated with the propagating wave. In the example in Fig. 2.2 the wave is polarized since the electric field and magnetic field exist in one direction only. In a dielectric optical waveguide, light propagates in plane polarized modes and the plane in which light is

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polarized is either vertical or horizontal to the direction of wave, as shown in Fig. 2.7 in fundamental mode.

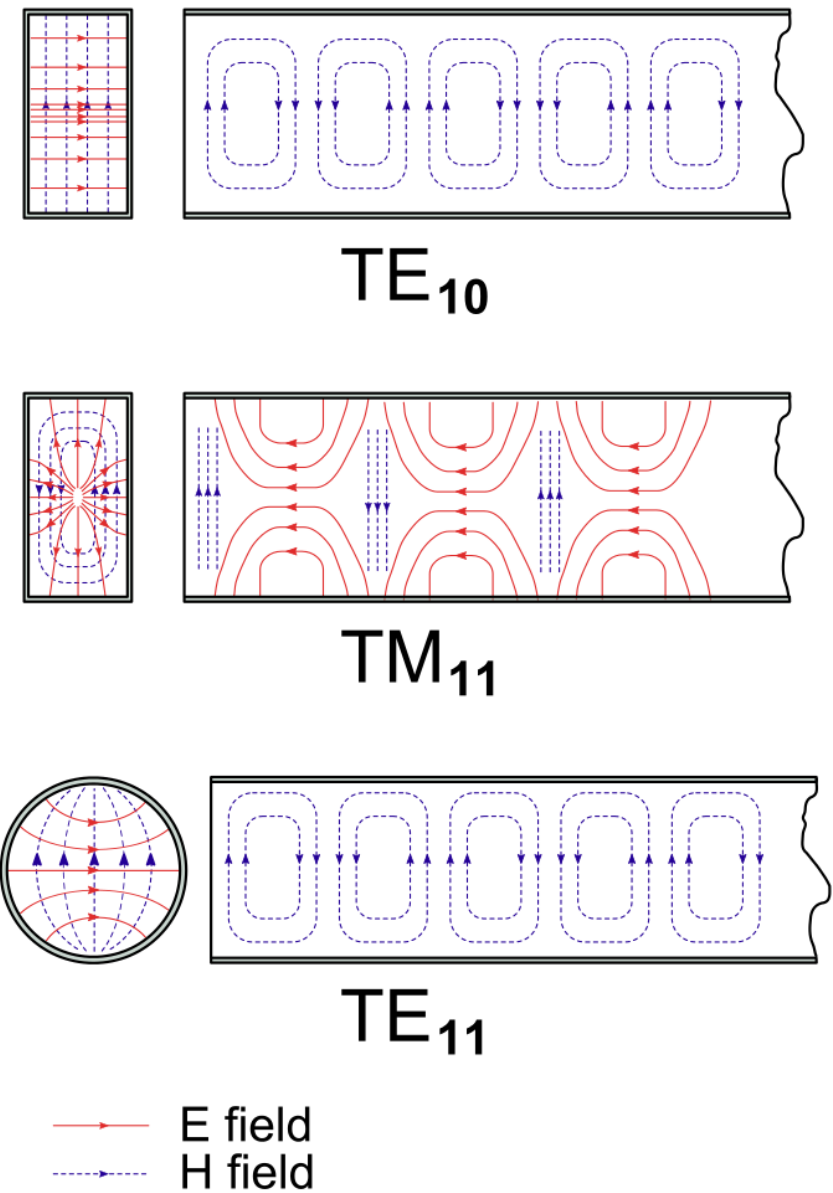


Figure 2.7: TE and TM modes in a waveguide

### 2.1.4.1 TE mode

TE mode is the fundamental mode in which there is no electric field in the direction of propagation of light. In Fig. 2.7 the electric field lines (blue) are perpendicular to

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the plane of incidence in TE mode. The plane of incidence is the plane in which optical waves strike the surface of the waveguide.

#### 2.1.4.2 TM mode

TM mode is the fundamental mode in which there is no magnetic field in the direction of propagation of light. In Fig. 2.7 it can be seen that magnetic field (red lines) are perpendicular to the plane of incidence in TM mode.

#### 2.1.5 Confinement factor

Often it is necessary to know the confined power inside the core of the waveguide which helps in figuring out the waveguide mode. The confinement is also a measure of the proportion of the power in a given mode that lies within the core [37].

$$\text{Confinement factor} = \frac{\int_{-H/2}^{H/2} E_x^2(y) dy}{\int_{-\infty}^{\infty} E_x^2(y) dy} \quad (2.16)$$

Confinement factor is an important measure which is function of various factors like polarization, RI difference between the core and cladding, mode number etc.

#### 2.1.6 Jones calculus

Polarized light can be represented using Jones calculus. Polarized light is represented using *Jones vector* and linear optical elements are represented by *Jones matrices*. When light crosses an optical element the resulting polarization of the emerging light is found by taking the product of the Jones matrix of the optical element and the Jones vector of the incident light. *Jones calculus* is only applicable to light that is **already fully polarized** [38].

##### 2.1.6.1 Jones vector

The Jones vector describes the polarization of light in free space or another homogeneous isotropic non-attenuating medium, where the light can be properly described as transverse waves [38]. The Jones vector is a complex vector that is a mathematical representation of a real wave. A typical representation of the electric field for the optical wave described in 2.8 can be as follows:

$$E = \begin{pmatrix} E_x(t) \\ E_y(t) \\ 0 \end{pmatrix} = \begin{pmatrix} E_x e^{i(kz - \omega t + \phi_x)} \\ E_y e^{i(kz - \omega t + \phi_y)} \\ 0 \end{pmatrix} = \begin{pmatrix} E_x e^{i\phi_x} \\ E_y e^{i\phi_y} \\ 0 \end{pmatrix} e^{i(kz - \omega t)} \quad (2.17)$$

where  $\phi_x$  and  $\phi_y$  indicate the phasor notation. The Jones vector of the plane wave is described by:

$$\begin{pmatrix} E_x e^{i\phi_x} \\ E_y e^{i\phi_y} \end{pmatrix} \quad (2.18)$$

and the intensity of the optical,  $I$  wave can be written as,

$$I = |E_x|^2 + |E_y|^2 \quad (2.19)$$

Generally, when considering Jones vector a wave of unit intensity is required for the consideration polarization, so Jones vector is noted using an unit vector where,

$$E\overline{E} = 1 \quad (2.20)$$

where  $\overline{E}$  is the complex conjugate of  $E$ . In general the Jones representation of a normalized elliptically polarized beam with azimuth  $\theta$  and elliptical angle  $\epsilon$  is given by,

$$e^{i\phi} \begin{pmatrix} \cos \theta \cos \epsilon - j \sin \theta \sin \epsilon \\ \sin \theta \cos \epsilon - j \cos \theta \sin \epsilon \end{pmatrix} \quad (2.21)$$

where  $e^{i\phi}$  is an arbitrary phase vector and  $\phi = \phi_x - \phi_y$ . So, for example a linear polarization of TE mode can be represented as,

$$\begin{pmatrix} 1 \\ 0 \end{pmatrix} \quad (2.22)$$

since,  $\theta = 0$  and  $\epsilon = 0$ .

### 2.1.6.2 Jones matrix

Jones matrix are the formal representation of the various optical elements such as lenses, beam splitters, mirrors, phase retarders, polarizers at arbitrary angles that can modify polarization. They generally operate on Jones vector and helps in comprehend situations which light encounters multiple polarization elements in sequence. In these situations the products of the Jones matrices can be used to represent the transfer matrix. This situation can be represented using,

$$[E_{output}] = J_{system}[E_{input}] \quad (2.23)$$

where  $E_{input}$  is the input field into the optical system and  $E_{output}$  is the generated output field represented using Jones vector. The matrix  $J_{system}$  is the Jones matrix of the optical system comprising of a series of polarization devices. If there are  $N$  devices in the system then the final transfer matrix comes out as,

$$J_{system} = J_N J_{N-1} \dots J_2 J_1 \quad (2.24)$$

where  $J_N$  is the Jones matrix for  $n^{th}$  polarizing optical element.

### 2.1.7 Jones matrix for polarizing optical systems

To construct optical waveguides for polarization rotation it is imperative to deal with the basic principles of standard available optical systems. Here, the fundamental principles of polarizer and wave plates are interpreted using Jones calculus.

### 2.1.7.1 Polarizer

Polarizers have an index of refraction which depends on orientation electric field propagation. If any optical system has a transmission axis and an absorption axis for electric fields, then lights will be passed along the transmission axis and absorbed along the other axis. So, the Jones matrix of a polarizer making an angle  $\theta$  with the X-axis will come out as,

$$\begin{pmatrix} \cos^2 \theta & \sin \theta \cos \theta \\ \sin \theta \cos \theta & \sin^2 \theta \end{pmatrix} \quad (2.25)$$

### 2.1.7.2 Wave plates

Wave plates are phase retarders which are made of birefringent crystals. Wave plates can be conceptualized as two polarizers kept apart at certain distance  $d$ , such that their polarization axes are apart orthogonally ( $90^\circ$ ). The phase difference as light passes through this setup of thickness  $d$  is,

$$(k_{slow} - k_{fast}) d = \frac{2\pi d}{\lambda_{vac}} (n_{slow} - n_{fast}) \quad (2.26)$$

In, general the Jones matrix for a wave plate is given by,

$$\begin{pmatrix} \cos^2 \theta + \xi \sin^2 \theta & \sin \theta \cos \theta - \xi \sin \theta \cos \theta \\ \sin \theta \cos \theta - \xi \sin \theta \cos \theta & \sin^2 \theta + \xi \cos^2 \theta \end{pmatrix} \quad (2.27)$$

where  $\xi$  is calculated based on the type of wave plate. The following equations addresses some general scenarios:

$$\begin{cases} \xi = e^{i\pi/2}, & \text{where, } (k_{slow} - k_{fast}) d = \pi/2 + 2\pi m, \text{ for quarter-wave plate} \\ \xi = e^{i\pi}, & \text{where, } (k_{slow} - k_{fast}) d = \pi + 2\pi m, \text{ for half-wave plate} \end{cases} \quad (2.28)$$

Similar concept is used in the construction of PR waveguides which will be discussed in later sections shortly.

## 2.1.8 Poincaré sphere and state of polarization

To view a complete representation of all the polarization ellipses generated using Jones vectors, a spherical structure with unit radius is used, which is known as Poincaré sphere. If the orientation in space of the ellipse of polarization is determined by the azimuth,  $\theta$  and ellipticity,  $\epsilon$  then that point can be completely characterized by its longitude  $2\theta$  and latitude  $2\epsilon$ . The north and south poles represent the right-handed and left-handed circular polarization respectively. In general the diametrically opposite points represent pairs of orthogonal polarization. The SOP and its corresponding location in the Poincaré sphere is visualized in the Fig. 2.8. To go from one SOP to another the polarized light can be passed through various optical components which can be computed using the Jones matrix and the corresponding SOP can be depicted on the Poincaré sphere as well.

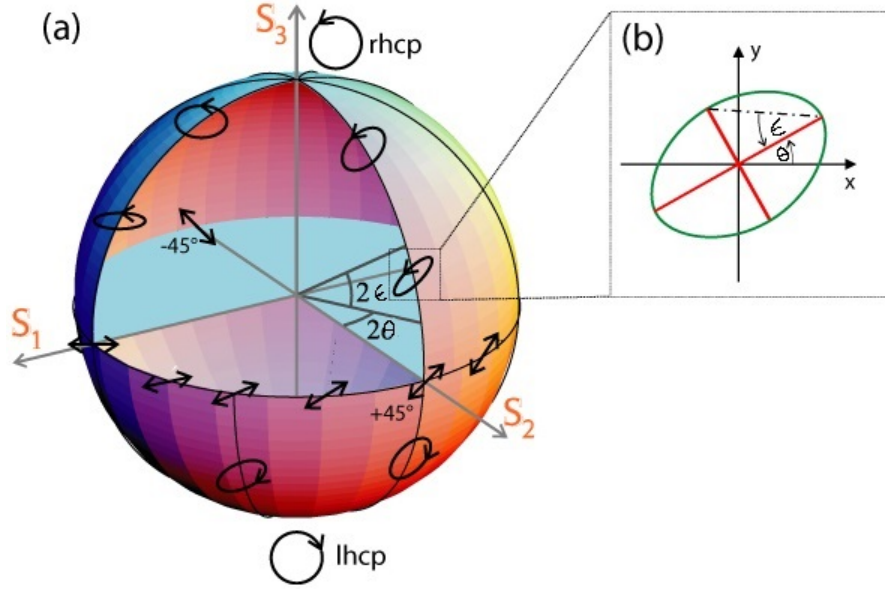


Figure 2.8: (a) Representation of the Poincaré sphere (b) Representation of the ellipse parameters [39]

The SOP of any wave is also defined using polarization extinction range/ratio (PER) and polarization phase,  $\phi$  given by the following equations:

$$\begin{aligned} PER_{TE-TM} &= 10 \log \frac{P_{TM}}{P_{TE}} \\ PER_{TM-TE} &= 10 \log \frac{P_{TE}}{P_{TM}} \\ \phi &= \phi_x - \phi_y \end{aligned} \quad (2.29)$$

For complete polarized light, the point on the Poincaré sphere must be fixed on time which requires,

$$\frac{E_x(t)}{E_y(t)} = \text{constant} \quad (2.30)$$

and,

$$\phi = \phi_x(t) - \phi_y(t) = \text{constant} \quad (2.31)$$

### 2.1.9 Stoke's parameter

Quasi-monochromatic waves are mathematically treated using Stokes parameters ( $S_0, S_1, S_2, S_3$ ), which constitute a vector generally known as Stokes vectors. Stokes vectors are used to keep track of the partial polarization (and attenuation) of a light beam in terms of total intensity ( $I$ ), degree of polarization ( $p$ ) and ellipse parameters, as the light progresses

through an optical system. A Stokes vector can generally be represented as,

$$\vec{S} = \begin{pmatrix} S_0 \\ S_1 \\ S_2 \\ S_3 \end{pmatrix} \quad (2.32)$$

where,

$$\begin{cases} S_0 = I \\ S_1 = I_p \cos 2\theta \cos 2\epsilon \\ S_2 = I_p \sin 2\theta \cos 2\epsilon \\ S_3 = I_p \sin 2\epsilon \end{cases} \quad (2.33)$$

Here,  $I_p, 2\theta, 2\epsilon$  are the spherical coordinates of the 3-D vector of Cartesian coordinates  $(S_1, S_2, S_3)$ . So, given the Stokes parameters, the spherical coordinates  $(p, 2\theta, 2\epsilon)$  can be obtained and represented by a point inside the Poincaré sphere using the following:

$$\begin{cases} I = S_0 \\ p = \frac{\sqrt{S_1^2 + S_2^2 + S_3^2}}{S_0} \\ 2\theta = \tan^{-1} \frac{S_2}{S_1} \\ 2\epsilon = \tan^{-1} \frac{S_3}{\sqrt{S_1^2 + S_2^2}} \end{cases} \quad (2.34)$$

The prescribed notations are portrayed on the Poincaré sphere in the following Fig. 2.9.

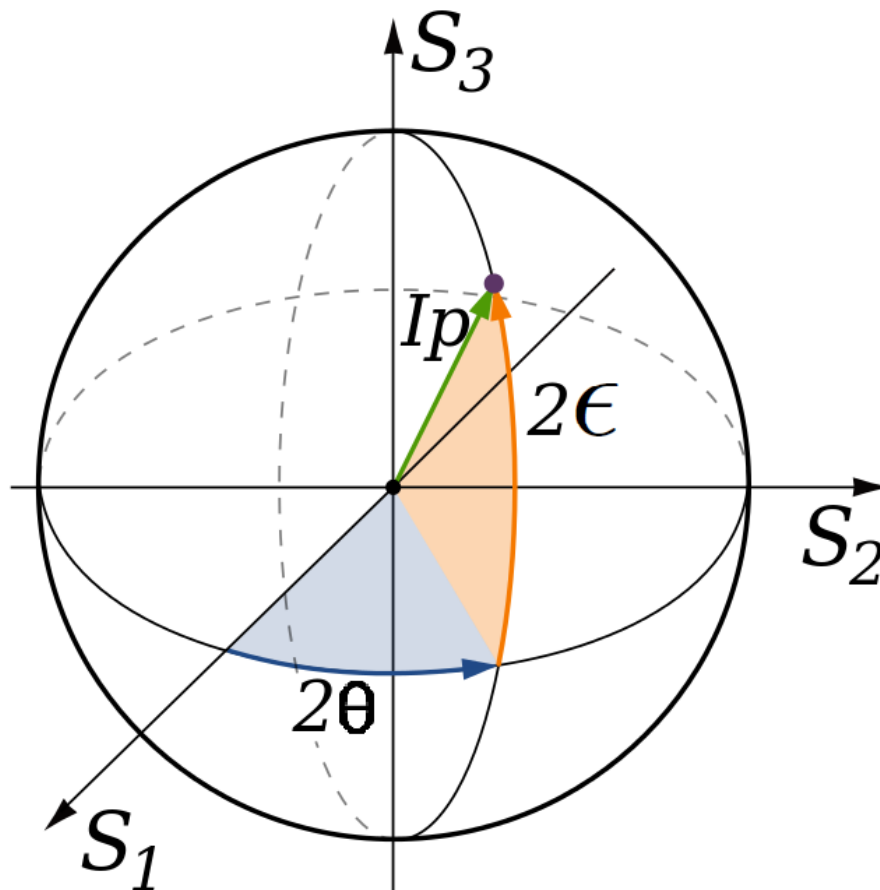


Figure 2.9: Poincaré sphere, on or beneath which the three Stokes parameters [ $S_1$ ,  $S_2$ ,  $S_3$ ] are plotted in Cartesian coordinates [40]

## 2.2 Tuning optical waveguide

### 2.2.1 Thermal mechanism

### 2.2.2 Liquid crystals

### 2.2.3 Current injection

### 2.2.4 MEMS

Actuation principle...

## **2.3 Polarization rotator (PR)**

### **2.3.1 Optical fiber PR**

### **2.3.2 Integrated circuit PR**

The currently available IC PRs can be classified under two categories as passive and active PR. In the passive PRs the waveguide structures are designed in a specific way to manipulate the effective RI of the waveguide to obtain the desired polarization. The structures cannot be manipulated or tuned once fabricated. Whereas, in active PRs, the effective RI is manipulated by applying voltage to a fixed waveguide structure and using quantum optical phenomenon.

#### **2.3.2.1 Passive PR**

The currently, available passive PRs are based on the principles of mode evolution [41, 30, 42, 43, 44], mode coupling [28, 45, 27] and mode hybridization [46, 26, 47, 25].

**Mode evolution**

**Mode coupling**

**Mode hybridization**

#### **2.3.2.2 Active PR**

#### **2.3.2.3 Comparative analysis of available polarization rotator**

# **3**

Chapter 3

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## **Design and simulation**

### **3.1 Approach**

### **3.2 Designing the experiment**

#### **3.2.1 Design principle**

#### **3.2.2 Use case: Active polarization rotator**

### **3.3 Choice of simulation**

### **3.4 Simulation results and analysis**



# 4

Chapter 4

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## Fabrication

# **5**

Chapter 5

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## **Interpreting the design**

**5.1 Experimental setup for measurement**

**5.2 Optical coupling**

**5.3 Results**

**5.4 Analysis**

# 6

Chapter 6

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## Conclusions

# **7**

Chapter 7

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## **Limitations and future work**

### **7.1 Limitations**

### **7.2 Future work**

# Todo list

May be update the picture using CST . . . . .	12
Include diagram from my own simulations . . . . .	13

# Abbreviations

<b>BPM</b>	Beam propagation method.	10
<b>CAGR</b>	Compound annual growth rate.	3
<b>CMOS</b>	Complementary metal-oxide semiconductor.	3
<b>EM</b>	Electromagnetic.	6–8, 12
<b>FDTD</b>	Finite difference time domain.	10
<b>FEM</b>	Finite element modeling.	10
<b>IC</b>	Integrated circuit(s).	2, 3, 5, 20
<b>IMS</b>	IP Multimedia Subsystem.	2
<b>IoT</b>	Internet of Things.	1
<b>MEMS</b>	Microelectromechanical systems.	4, 5
<b>OEIC</b>	Optoelectronic integrated circuit.	4
<b>PD<math>\lambda</math></b>	Polarization dependent wavelength characteristics.	4
<b>PDL</b>	Polarization dependent loss.	4
<b>PER</b>	polarization extinction range/ratio.	17
<b>PMD</b>	Polarization mode dispersion.	4
<b>PR</b>	Polarization rotator.	4, 6, 16, 20
<b>RI</b>	Refractive index.	4, 8, 9, 11, 14, 20
<b>SMC</b>	Single-mode condition.	10
<b>SOI</b>	Silicon on Insulator.	3, 4
<b>SOP</b>	State of polarization.	6, 16, 17

**TE** Tansverse Electric. 9, 10, 12–15

**TEM** Tansverse Electromagnetic. 8, 12

**TM** Tansverse Magnetic. 9, 10, 12–14

**TPR** Tunable polarization rotator. 4

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